



Reverse Voltage: 22 to 43 V
Peak Pulse Power: 8000 W

Axial Lead Transient Voltage Suppressors

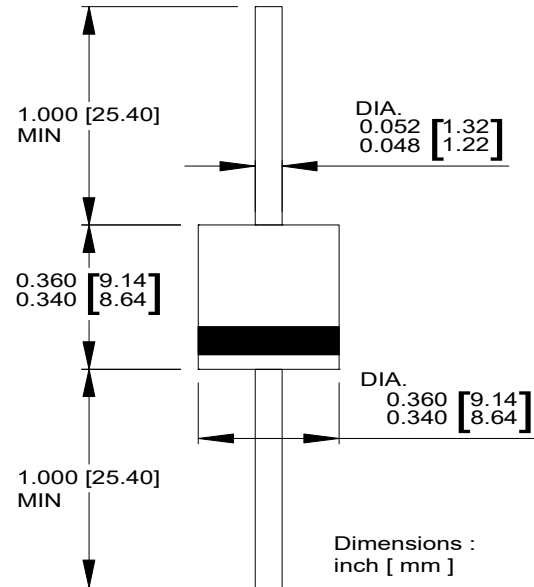
Features

- Glass passivated chip
- 8000 W peak pulse power capability with a 10/1000 μ s waveform, repetitive rate (duty cycle):0.01 %
- Low leakage
- Uni and Bidirectional unit
- Excellent clamping capability
- Very fast response time
- RoHS compliant

Mechanical Data

- Case: Molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead: Solderable per MIL-STD-202, method 208 guaranteed
- Polarity: Color band denotes cathode end except Bipolar
- Mounting position: Any

R-6/P600



Maximum Ratings($T_A=25^\circ\text{C}$ unless otherwise noted)

Product	Breakdown voltage VBR (Volts) @ IT (mA)			Working PeakReverse Voltage V_{RWM} (Volts)	Maximum Reverse Leakage @ V_{RWM} IR(μ A)	Maximum Clamping Voltage @ I_{pp} V_C (Volts)	Peak Pulse Current with a 10/1000 waveform Ipp(Amps)
	Min.	Max.	IT				
8KP22(C)A	24.4	26.9	5	22	5	35.5	225
8KP24(C)A	26.7	29.5	5	24	5	38.9	206
8KP30(C)A	33.3	36.8	5	30	5	48.4	165
8KP33(C)A	36.7	40.6	5	33	5	53.3	150
8KP36(C)A	40	44.2	5	36	5	58.1	138
8KP40(C)A	44.4	49.1	5	40	5	64.5	124
8KP43(C)A	47.8	52.8	5	43	5	69.4	115

Parameter	Symbol	Value	UNIT
Peak power dissipation with a 10/1000 μ s waveform ⁽¹⁾	P_{PP}	8000	W
Peak pulse current with a 10/1000 μ s waveform ⁽¹⁾	I_{PP}	See Next Table	A
Power dissipation on infinite heatsink at $T_L = 75^\circ\text{C}$	P_D	8.0	W
Peak forward surge current, 8.3 ms single half sine-wave unidirectional only ⁽²⁾	I_{FSM}	500	A
Operating junction and storage temperature range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Note:

(1)Non-repetitive current pulse per Fig.5 and derated above $T_A = 25^\circ\text{C}$ per Fig.1

(2)Measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum